



**OPTICALLY COUPLED  
 ISOLATOR  
 PHOTOTRANSISTOR OUTPUT**

**APPROVALS**

- UL recognised, File No. E91231
- 'X' SPECIFICATION APPROVALS
- VDE 0884 in 3 available lead form :-
  - STD
  - G form
  - SMD approved to CECC 00802
- Certified to EN60950 by the following Test Bodies :-
  - Nemko - Certificate No. P01102464
  - Fimko - Certificate No. FI18166
  - Semko - Reference No. 0202037/01-22
  - Demko - Certificate No. 311158-01
- BSI approved - Certificate No. 8001

**DESCRIPTION**

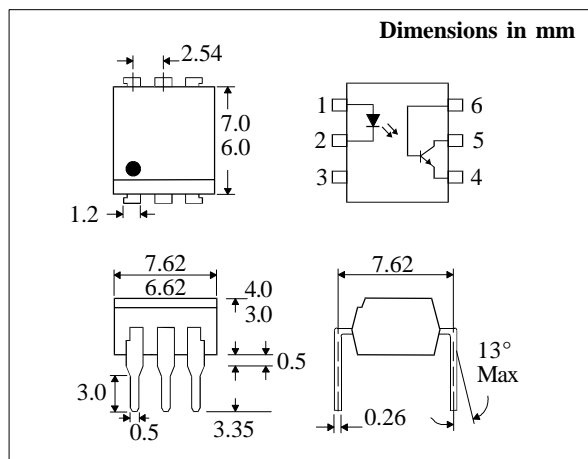
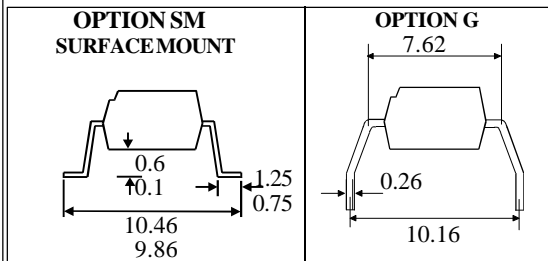
The H11AV series of optically coupled isolators consist of infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

**FEATURES**

- Options :-
  - 10mm lead spread - add G after part no.
  - Surface mount - add SM after part no.
  - Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV<sub>RMS</sub>, 7.5kV<sub>PK</sub>)
- High BV<sub>CEO</sub> (70V min)
- All electrical parameters 100% tested
- Custom electrical selections available

**APPLICATIONS**

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



**ABSOLUTE MAXIMUM RATINGS  
 (25°C unless otherwise specified)**

Storage Temperature	-55°C to + 150°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

**INPUT DIODE**

Forward Current	60mA
Reverse Voltage	6V
Power Dissipation	105mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage BV <sub>CEO</sub>	70V
Collector-base Voltage BV <sub>CBO</sub>	70V
Emitter-collector Voltage BV <sub>ECO</sub>	6V
Power Dissipation	160mW

**POWER DISSIPATION**

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

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**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ )		1.2	1.5	V	$I_F = 10\text{mA}$
	Reverse Current ( $I_R$ )			10	$\mu\text{A}$	$V_R = 6\text{V}$
Output	Collector-emitter Breakdown ( $BV_{CEO}$ ) ( note 2 )	70			V	$I_C = 1\text{mA}$
	Collector-base Breakdown ( $BV_{CBO}$ )	70			V	$I_C = 100\mu\text{A}$
	Emitter-collector Breakdown ( $BV_{ECO}$ )	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current ( $I_{CEO}$ )			50	nA	$V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) H11AV1	100		300	%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	H11AV2	50			%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	H11AV3	20			%	$10\text{mA } I_F, 10\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.4	V	$20\text{mA } I_F, 2\text{mA } I_C$
	Input to Output Isolation Voltage $V_{ISO}$	5300 7500			$V_{RMS}$ $V_{PK}$	See note 1 See note 1
	Input-output Isolation Resistance $R_{ISO}$	$5 \times 10^{10}$			$\Omega$	$V_{IO} = 500\text{V}$ (note 1)
	Rise Time, tr Fall Time, tf		2 2		$\mu\text{s}$ $\mu\text{s}$	$V_{CC} = 5\text{V}$ , fig 1 $I_F = 10\text{mA}, R_L = 75\Omega$

Note 1 Measured with input leads shorted together and output leads shorted together.  
 Note 2 Special Selections are available on request. Please consult the factory.

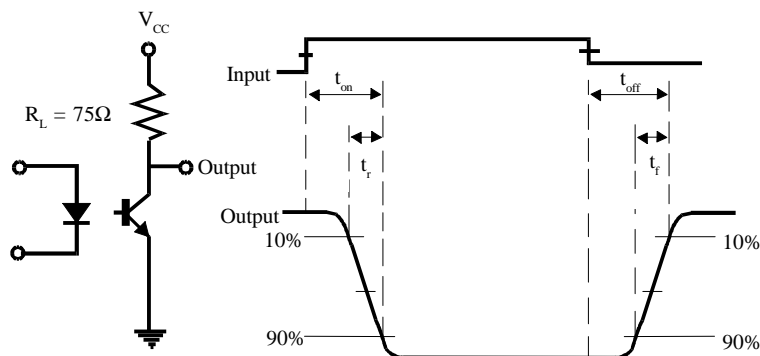
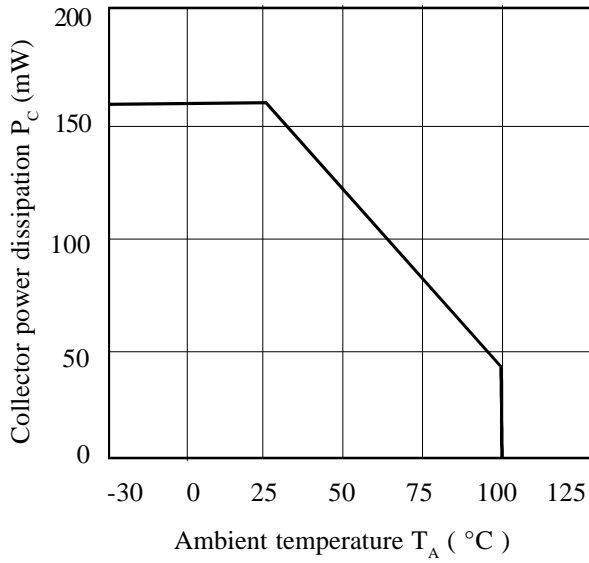
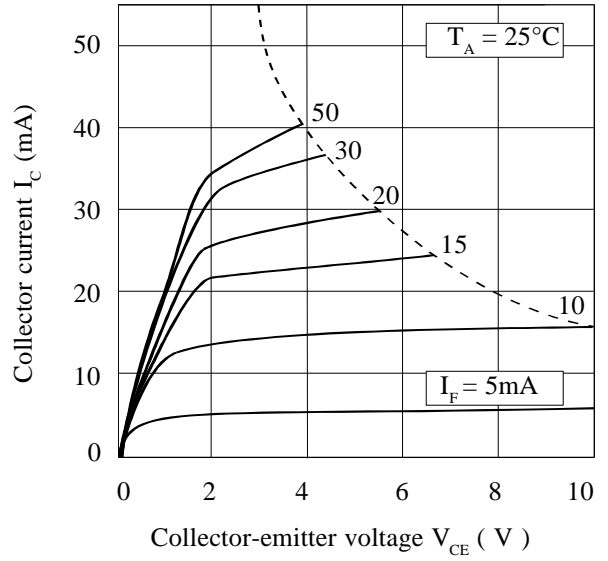


FIG 1

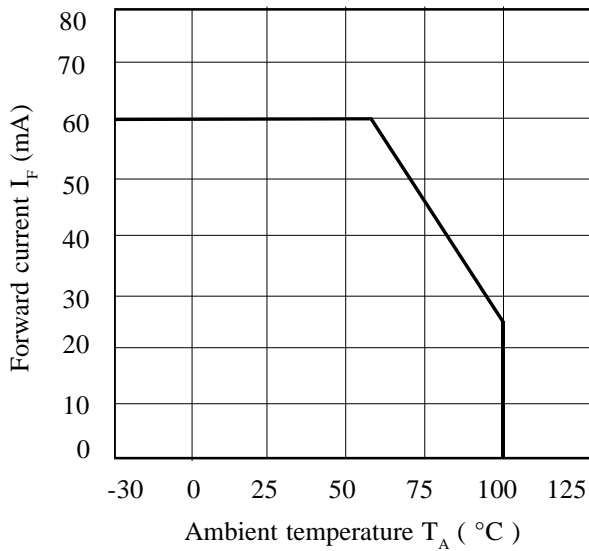
Collector Power Dissipation vs. Ambient Temperature



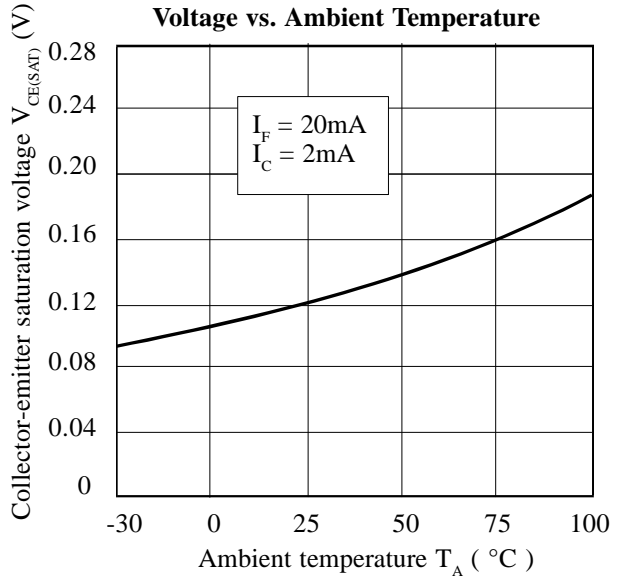
Collector Current vs. Collector-emitter Voltage



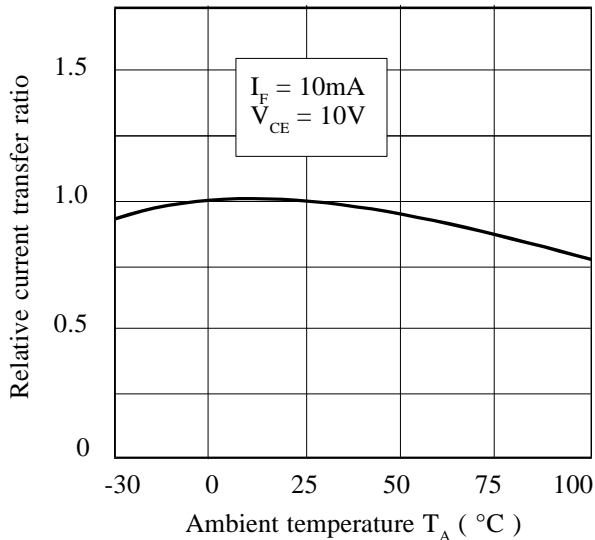
Forward Current vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature



Relative Current Transfer Ratio vs. Ambient Temperature



Relative Current Transfer Ratio vs. Forward Current

